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Team Nexperia

# 74AUP1G386

Low-power 3-input EXCLUSIVE-OR gate

Rev. 6 — 31 July 2012

Product data sheet

## 1. General description

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The 74AUP1G386 provides a single 3-input EXCLUSIVE-OR gate.

Schmitt trigger action at all inputs makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device ensures a very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and benefits

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- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- Complies with JEDEC standards:
  - ◆ JESD8-12 (0.8 V to 1.3 V)
  - ◆ JESD8-11 (0.9 V to 1.65 V)
  - ◆ JESD8-7 (1.2 V to 1.95 V)
  - ◆ JESD8-5 (1.8 V to 2.7 V)
  - ◆ JESD8-B (2.7 V to 3.6 V)
- ESD protection:
  - ◆ HBM JESD22-A114F Class 3A exceeds 5000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu\text{A}$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of  $V_{CC}$
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$



### 3. Ordering information

Table 1. Ordering information

| Type number  | Package           |       |   | Version |
|--------------|-------------------|-------|---|---------|
|              | Temperature range | Name  | Description   |         |
| 74AUP1G386GW | -40 °C to +125 °C | SC-88 | plastic surface-mounted package; 6 leads  | SOT363  |
| 74AUP1G386GM | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm | SOT886  |
| 74AUP1G386GF | -40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm    | SOT891  |
| 74AUP1G386GN | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm       | SOT1115 |
| 74AUP1G386GS | -40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm       | SOT1202 |

### 4. Marking

Table 2. Marking

| Type number  | Marking code <sup>[1]</sup> |
|--------------|-----------------------------|
| 74AUP1G386GW | aH                          |
| 74AUP1G386GM | aH                          |
| 74AUP1G386GF | aH                          |
| 74AUP1G386GN | aH                          |
| 74AUP1G386GS | aH                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

### 5. Functional diagram

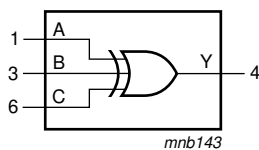


Fig 1. Logic symbol

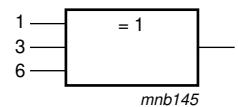


Fig 2. IEC logic symbol

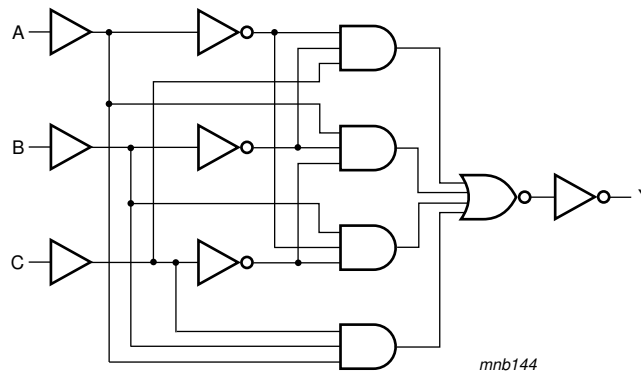


Fig 3. Logic diagram

## 6. Pinning information

### 6.1 Pinning

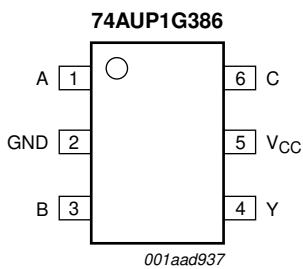


Fig 4. Pin configuration SOT363

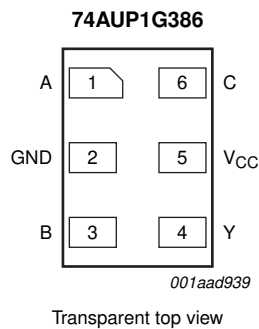


Fig 5. Pin configuration SOT886

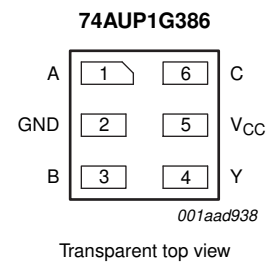


Fig 6. Pin configuration SOT891, SOT1115 and SOT1202

### 6.2 Pin description

Table 3. Pin description

| Symbol          | Pin | Description    |
|-----------------|-----|----------------|
| A               | 1   | data input A   |
| GND             | 2   | ground (0 V)   |
| B               | 3   | data input B   |
| Y               | 4   | data output Y  |
| V <sub>CC</sub> | 5   | supply voltage |
| C               | 6   | data input C   |

## 7. Functional description

Table 4. Function table<sup>[1]</sup>

| Input |   |   | Output |
|-------|---|---|--------|
| A     | B | C | Y      |
| L     | L | L | L      |
| L     | L | H | H      |
| L     | H | L | H      |
| L     | H | H | L      |
| H     | L | L | H      |
| H     | L | H | L      |
| H     | H | L | L      |
| H     | H | H | H      |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

## 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                      | Min                 | Max      | Unit |
|-----------|-------------------------|---------------------------------|---------------------|----------|------|
| $V_{CC}$  | supply voltage          |                                 | -0.5                | +4.6     | V    |
| $I_{IK}$  | input clamping current  | $V_I < 0$ V                     | -50                 | -        | mA   |
| $V_I$     | input voltage           |                                 | <sup>[1]</sup> -0.5 | +4.6     | V    |
| $I_{OK}$  | output clamping current | $V_O < 0$ V                     | -50                 | -        | mA   |
| $V_O$     | output voltage          | Active mode and Power-down mode | <sup>[1]</sup> -0.5 | +4.6     | V    |
| $I_O$     | output current          | $V_O = 0$ V to $V_{CC}$         | -                   | $\pm 20$ | mA   |
| $I_{CC}$  | supply current          |                                 | -                   | 50       | mA   |
| $I_{GND}$ | ground current          |                                 | -50                 | -        | mA   |
| $T_{stg}$ | storage temperature     |                                 | -65                 | +150     | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C   | <sup>[2]</sup> -    | 250      | mW   |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 packages: above 87.5 °C the value of  $P_{tot}$  derates linearly with 4.0 mW/K.

For XSON6 packages: above 118 °C the value of  $P_{tot}$  derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol   | Parameter      | Conditions | Min | Max | Unit |
|----------|----------------|------------|-----|-----|------|
| $V_{CC}$ | supply voltage |            | 0.8 | 3.6 | V    |
| $V_I$    | input voltage  |            | 0   | 3.6 | V    |

Table 6. Recommended operating conditions ...continued

| Symbol           | Parameter                           | Conditions                             | Min | Max             | Unit |
|------------------|-------------------------------------|--|-----|-----------------|------|
| V <sub>O</sub>   | output voltage                      | Active mode                            | 0   | V <sub>CC</sub> | V    |
|                  |                                     | Power-down mode; V <sub>CC</sub> = 0 V | 0   | 3.6             | V    |
| T <sub>amb</sub> | ambient temperature                 |  | -40 | +125            | °C   |
| Δt/ΔV            | input transition rise and fall rate | V <sub>CC</sub> = 0.8 V to 3.6 V       | 0   | 200             | ns/V |

## 10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                         | Parameter                            | Conditions  | Min                    | Typ | Max                    | Unit |
|--------------------------------|--------------------------------------|---|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = 25 °C</b> |                                      |   |                        |     |                        |      |
| V <sub>IH</sub>                | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V   | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | 0.65 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | 1.6                    | -   | -                      | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V   | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|                                |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V   | -                      | -   | 0.35 × V <sub>CC</sub> | V    |
|                                |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V  | -                      | -   | 0.7                    | V    |
|                                |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V  | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                             |                        |     |                        |      |
|                                |                                      | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V                       | V <sub>CC</sub> - 0.1  | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                               | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                               | 1.11                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                              | 1.32                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                               | 2.05                   | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                               | 1.9                    | -   | -                      | V    |
|                                |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                               | 2.72                   | -   | -                      | V    |
| V <sub>OL</sub>                | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>                             |                        |     |                        |      |
|                                |                                      | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V                        | -                      | -   | 0.1                    | V    |
|                                |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                                | -                      | -   | 0.3 × V <sub>CC</sub>  | V    |
|                                |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                                | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                               | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                                | -                      | -   | 0.31                   | V    |
|                                |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                                | -                      | -   | 0.44                   | V    |
|                                |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                                | -                      | -   | 0.31                   | V    |
| I <sub>I</sub>                 | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                   | -                      | -   | ±0.1                   | μA   |
| I <sub>OFF</sub>               | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V          | -                      | -   | ±0.2                   | μA   |
| ΔI <sub>OFF</sub>              | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V | -                      | -   | ±0.2                   | μA   |

**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol   | Parameter                            | Conditions  | Min                  | Typ | Max                  | Unit          |
|--|--------------------------------------|---|----------------------|-----|----------------------|---------------|
| $I_{CC}$   | supply current                       | $V_I = \text{GND or } V_{CC}; I_O = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$    | -                    | -   | 0.5                  | $\mu\text{A}$ |
| $\Delta I_{CC}$  | additional supply current            | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$                     | -                    | -   | 40                   | $\mu\text{A}$ |
| $C_I$  | input capacitance                    | $V_{CC} = 0 \text{ V to } 3.6 \text{ V}; V_I = \text{GND or } V_{CC}$                         | -                    | 0.8 | -                    | $\text{pF}$   |
| $C_O$  | output capacitance                   | $V_O = \text{GND}; V_{CC} = 0 \text{ V}$  | -                    | 1.7 | -                    | $\text{pF}$   |
| <b><math>T_{\text{amb}} = -40 \text{ }^\circ\text{C to } +85 \text{ }^\circ\text{C}</math></b> |                                      |   |                      |     |                      |               |
| $V_{IH}$   | HIGH-level input voltage             | $V_{CC} = 0.8 \text{ V}$  | $0.70 \times V_{CC}$ | -   | -                    | V             |
|  |                                      | $V_{CC} = 0.9 \text{ V to } 1.95 \text{ V}$   | $0.65 \times V_{CC}$ | -   | -                    | V             |
|  |                                      | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$  | 1.6                  | -   | -                    | V             |
|  |                                      | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$  | 2.0                  | -   | -                    | V             |
| $V_{IL}$   | LOW-level input voltage              | $V_{CC} = 0.8 \text{ V}$  | -                    | -   | $0.30 \times V_{CC}$ | V             |
|  |                                      | $V_{CC} = 0.9 \text{ V to } 1.95 \text{ V}$   | -                    | -   | $0.35 \times V_{CC}$ | V             |
|  |                                      | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$  | -                    | -   | 0.7                  | V             |
|  |                                      | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$  | -                    | -   | 0.9                  | V             |
| $V_{OH}$   | HIGH-level output voltage            | $V_I = V_{IH} \text{ or } V_{IL}$   |                      |     |                      |               |
|  |                                      | $I_O = -20 \mu\text{A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$                             | $V_{CC} - 0.1$       | -   | -                    | V             |
|  |                                      | $I_O = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$   | $0.7 \times V_{CC}$  | -   | -                    | V             |
|  |                                      | $I_O = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$   | 1.03                 | -   | -                    | V             |
|  |                                      | $I_O = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$  | 1.30                 | -   | -                    | V             |
|  |                                      | $I_O = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$   | 1.97                 | -   | -                    | V             |
|  |                                      | $I_O = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$   | 1.85                 | -   | -                    | V             |
|  |                                      | $I_O = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$   | 2.67                 | -   | -                    | V             |
| $V_{OL}$   | LOW-level output voltage             | $V_I = V_{IH} \text{ or } V_{IL}$   |                      |     |                      |               |
|  |                                      | $I_O = 20 \mu\text{A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$                              | -                    | -   | 0.1                  | V             |
|  |                                      | $I_O = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$  | -                    | -   | $0.3 \times V_{CC}$  | V             |
|  |                                      | $I_O = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$  | -                    | -   | 0.37                 | V             |
|  |                                      | $I_O = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$   | -                    | -   | 0.35                 | V             |
|  |                                      | $I_O = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$  | -                    | -   | 0.33                 | V             |
|  |                                      | $I_O = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$  | -                    | -   | 0.45                 | V             |
|  |                                      | $I_O = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$  | -                    | -   | 0.33                 | V             |
| $I_I$  | input leakage current                | $V_I = \text{GND to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$                  | -                    | -   | $\pm 0.5$            | $\mu\text{A}$ |
|  |                                      | $V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$                   | -                    | -   | $\pm 0.5$            | $\mu\text{A}$ |
| $I_{OFF}$  | power-off leakage current            | $V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$                   | -                    | -   | $\pm 0.5$            | $\mu\text{A}$ |
| $\Delta I_{OFF}$   | additional power-off leakage current | $V_I \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 0.2 \text{ V}$ | -                    | -   | $\pm 0.6$            | $\mu\text{A}$ |
| $I_{CC}$   | supply current                       | $V_I = \text{GND or } V_{CC}; I_O = 0 \text{ A}; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$    | -                    | -   | 0.9                  | $\mu\text{A}$ |
| $\Delta I_{CC}$  | additional supply current            | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$                     | -                    | -   | 50                   | $\mu\text{A}$ |



**Table 7. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                                     | Parameter                            | Conditions   | Min                    | Typ | Max                    | Unit |
|--|--------------------------------------|--|------------------------|-----|------------------------|------|
| <b>T<sub>amb</sub> = -40 °C to +125 °C</b> |                                      |  |                        |     |                        |      |
| V <sub>IH</sub>                            | HIGH-level input voltage             | V <sub>CC</sub> = 0.8 V  | 0.75 × V <sub>CC</sub> | -   | -                      | V    |
|  |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V  | 0.70 × V <sub>CC</sub> | -   | -                      | V    |
|  |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.6                    | -   | -                      | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 2.0                    | -   | -                      | V    |
| V <sub>IL</sub>                            | LOW-level input voltage              | V <sub>CC</sub> = 0.8 V  | -                      | -   | 0.25 × V <sub>CC</sub> | V    |
|  |                                      | V <sub>CC</sub> = 0.9 V to 1.95 V  | -                      | -   | 0.30 × V <sub>CC</sub> | V    |
|  |                                      | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                      | -   | 0.7                    | V    |
|  |                                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | -                      | -   | 0.9                    | V    |
| V <sub>OH</sub>                            | HIGH-level output voltage            | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |                        |     |                        |      |
|  |                                      | I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V  | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V  | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V  | 0.93                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V   | 1.17                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V  | 1.77                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V  | 1.67                   | -   | -                      | V    |
|  |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V  | 2.40                   | -   | -                      | V    |
| V <sub>OL</sub>                            | LOW-level output voltage             | V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>  |                        |     |                        |      |
|  |                                      | I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V   | -                      | -   | 0.11                   | V    |
|  |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V   | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|  |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V   | -                      | -   | 0.41                   | V    |
|  |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V  | -                      | -   | 0.39                   | V    |
|  |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V   | -                      | -   | 0.36                   | V    |
|  |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V   | -                      | -   | 0.50                   | V    |
|  |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V   | -                      | -   | 0.36                   | V    |
| I <sub>I</sub>                             | input leakage current                | V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V                                    | -                      | -   | ±0.75                  | μA   |
| I <sub>OFF</sub>                           | power-off leakage current            | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V                           | -                      | -   | ±0.75                  | μA   |
| ΔI <sub>OFF</sub>                          | additional power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V                  | -                      | -   | ±0.75                  | μA   |
| I <sub>CC</sub>                            | supply current                       | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V | -                      | -   | 1.4                    | μA   |
| ΔI <sub>CC</sub>                           | additional supply current            | V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 3.3 V          | -                      | -   | 75                     | μA   |

## 11. Dynamic characteristics

**Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

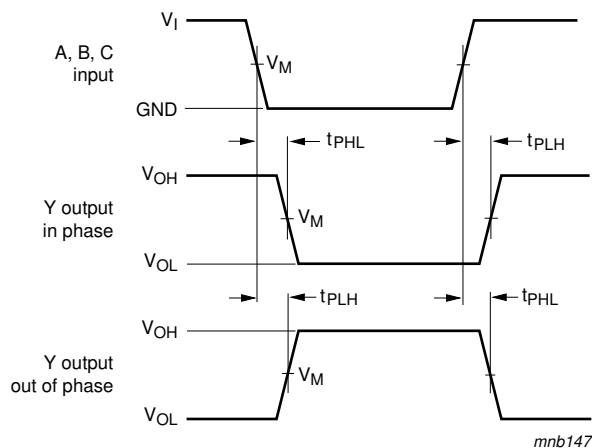
| Symbol                       | Parameter         | Conditions   | 25 °C |                    |      | -40 °C to +125 °C |             |              | Unit |
|------------------------------|-------------------|--|-------|--------------------|------|-------------------|-------------|--------------|------|
|                              |                   |  | Min   | Typ <sup>[1]</sup> | Max  | Min               | Max (85 °C) | Max (125 °C) |      |
| <b>C<sub>L</sub> = 5 pF</b>  |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | A, B and C to Y; see <a href="#">Figure 7</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                                      | -     | 23.4               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                             | 2.7   | 6.5                | 14.2 | 2.4               | 14.6        | 14.7         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                             | 2.0   | 4.4                | 8.1  | 2.1               | 8.8         | 9.1          | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                           | 1.8   | 3.5                | 6.1  | 1.6               | 7.0         | 7.3          | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                             | 1.5   | 2.7                | 4.3  | 1.2               | 4.6         | 4.8          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                             | 1.3   | 2.4                | 3.6  | 1.0               | 4.0         | 4.2          | ns   |
| <b>C<sub>L</sub> = 10 pF</b> |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | A, B and C to Y; see <a href="#">Figure 7</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                                      | -     | 26.8               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                             | 3.2   | 7.3                | 15.8 | 2.7               | 16.2        | 16.3         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                             | 2.3   | 5.0                | 9.0  | 2.5               | 9.8         | 10.2         | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                           | 2.2   | 4.1                | 6.9  | 1.9               | 7.8         | 8.2          | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                             | 1.9   | 3.2                | 5.0  | 1.6               | 5.3         | 5.5          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                             | 1.7   | 2.9                | 4.3  | 1.4               | 4.7         | 4.9          | ns   |
| <b>C<sub>L</sub> = 15 pF</b> |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | A, B and C to Y; see <a href="#">Figure 7</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                                      | -     | 30.1               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                             | 3.5   | 8.1                | 17.3 | 3.0               | 17.7        | 17.8         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                             | 2.6   | 5.6                | 9.8  | 2.8               | 10.7        | 11.1         | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                           | 2.4   | 4.6                | 7.5  | 2.2               | 8.6         | 9.0          | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                             | 2.2   | 3.7                | 5.5  | 1.9               | 5.9         | 6.2          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                             | 2.0   | 3.4                | 4.8  | 1.7               | 5.2         | 5.5          | ns   |
| <b>C<sub>L</sub> = 30 pF</b> |                   |  |       |                    |      |                   |             |              |      |
| t <sub>pd</sub>              | propagation delay | A, B and C to Y; see <a href="#">Figure 7</a> <sup>[2]</sup> |       |                    |      |                   |             |              |      |
|                              |                   | V <sub>CC</sub> = 0.8 V                                      | -     | 37.9               | -    | -                 | -           | -            | ns   |
|                              |                   | V <sub>CC</sub> = 1.1 V to 1.3 V                             | 4.5   | 10.3               | 21.6 | 3.9               | 22.0        | 22.1         | ns   |
|                              |                   | V <sub>CC</sub> = 1.4 V to 1.6 V                             | 3.5   | 7.1                | 12.1 | 3.5               | 13.2        | 13.8         | ns   |
|                              |                   | V <sub>CC</sub> = 1.65 V to 1.95 V                           | 3.1   | 5.8                | 9.5  | 2.8               | 10.7        | 11.3         | ns   |
|                              |                   | V <sub>CC</sub> = 2.3 V to 2.7 V                             | 2.9   | 4.8                | 6.9  | 2.6               | 7.8         | 8.2          | ns   |
|                              |                   | V <sub>CC</sub> = 3.0 V to 3.6 V                             | 2.7   | 4.5                | 6.1  | 2.3               | 6.6         | 6.9          | ns   |

**Table 8. Dynamic characteristics ...continued**  
 Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 8](#).

| Symbol  | Parameter                     | Conditions  | 25 °C |                    |     | -40 °C to +125 °C |             |              | Unit |
|---|-------------------------------|---|-------|--------------------|-----|-------------------|-------------|--------------|------|
|   |                               |   | Min   | Typ <sup>[1]</sup> | Max | Min               | Max (85 °C) | Max (125 °C) |      |
| <b>C<sub>L</sub> = 5 pF, 10 pF, 15 pF and 30 pF</b> |                               |   |       |                    |     |                   |             |              |      |
| C <sub>PD</sub>                                     | power dissipation capacitance | f <sub>i</sub> = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> <sup>[3][4]</sup> |       |                    |     |                   |             |              |      |
|   |                               | V <sub>CC</sub> = 0.8 V   | -     | 2.9                | -   | -                 | -           | -            | pF   |
|   |                               | V <sub>CC</sub> = 1.1 V to 1.3 V  | -     | 3.0                | -   | -                 | -           | -            | pF   |
|   |                               | V <sub>CC</sub> = 1.4 V to 1.6 V  | -     | 3.1                | -   | -                 | -           | -            | pF   |
|   |                               | V <sub>CC</sub> = 1.65 V to 1.95 V  | -     | 3.3                | -   | -                 | -           | -            | pF   |
|   |                               | V <sub>CC</sub> = 2.3 V to 2.7 V  | -     | 3.9                | -   | -                 | -           | -            | pF   |
|   |                               | V <sub>CC</sub> = 3.0 V to 3.6 V  | -     | 4.4                | -   | -                 | -           | -            | pF   |

- [1] All typical values are measured at nominal V<sub>CC</sub>.
- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
- [3] All specified values are the average typical values over all stated loads.
- [4] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).  
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:  
 f<sub>i</sub> = input frequency in MHz;  
 f<sub>o</sub> = output frequency in MHz;  
 C<sub>L</sub> = load capacitance in pF;  
 V<sub>CC</sub> = supply voltage in V;  
 N = number of inputs switching;  
 Σ(C<sub>L</sub> × V<sub>CC</sub><sup>2</sup> × f<sub>o</sub>) = sum of the outputs.

## 12. Waveforms

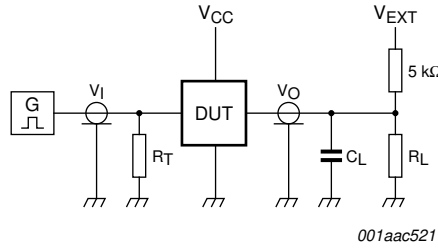


Measurement points are given in [Table 9](#).  
 Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

**Fig 7. Input A, B and C to output Y propagation delay times**

Table 9. Measurement points

| Supply voltage | Output              | Input               |          |               |
|----------------|---------------------|---------------------|----------|---------------|
| $V_{CC}$       | $V_M$               | $V_M$               | $V_I$    | $t_r = t_f$   |
| 0.8 V to 3.6 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | $V_{CC}$ | $\leq 3.0$ ns |



Test data is given in [Table 10](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Load                         |              | $V_{EXT}$          |                    |                    |
|----------------|------------------------------|--------------|--------------------|--------------------|--------------------|
| $V_{CC}$       | $C_L$                        | $R_L$ [1]    | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ | open               | GND                | $2 \times V_{CC}$  |

[1] For measuring enable and disable times  $R_L = 5$  kΩ, for measuring propagation delays, setup and hold times and pulse width  $R_L = 1$  MΩ.

13. Package outline

Plastic surface-mounted package; 6 leads

SOT363

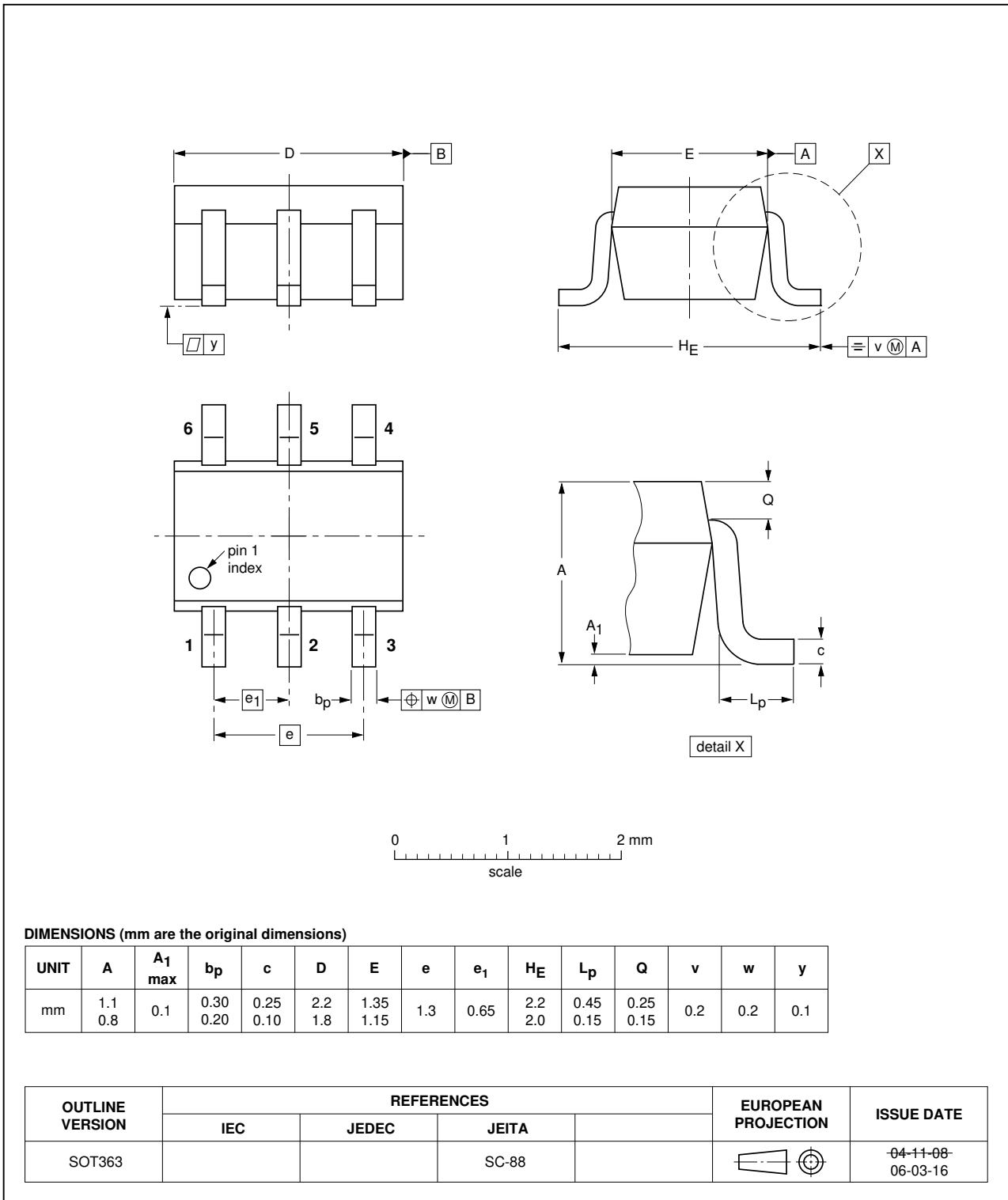


Fig 9. Package outline SOT363 (SC-88)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886

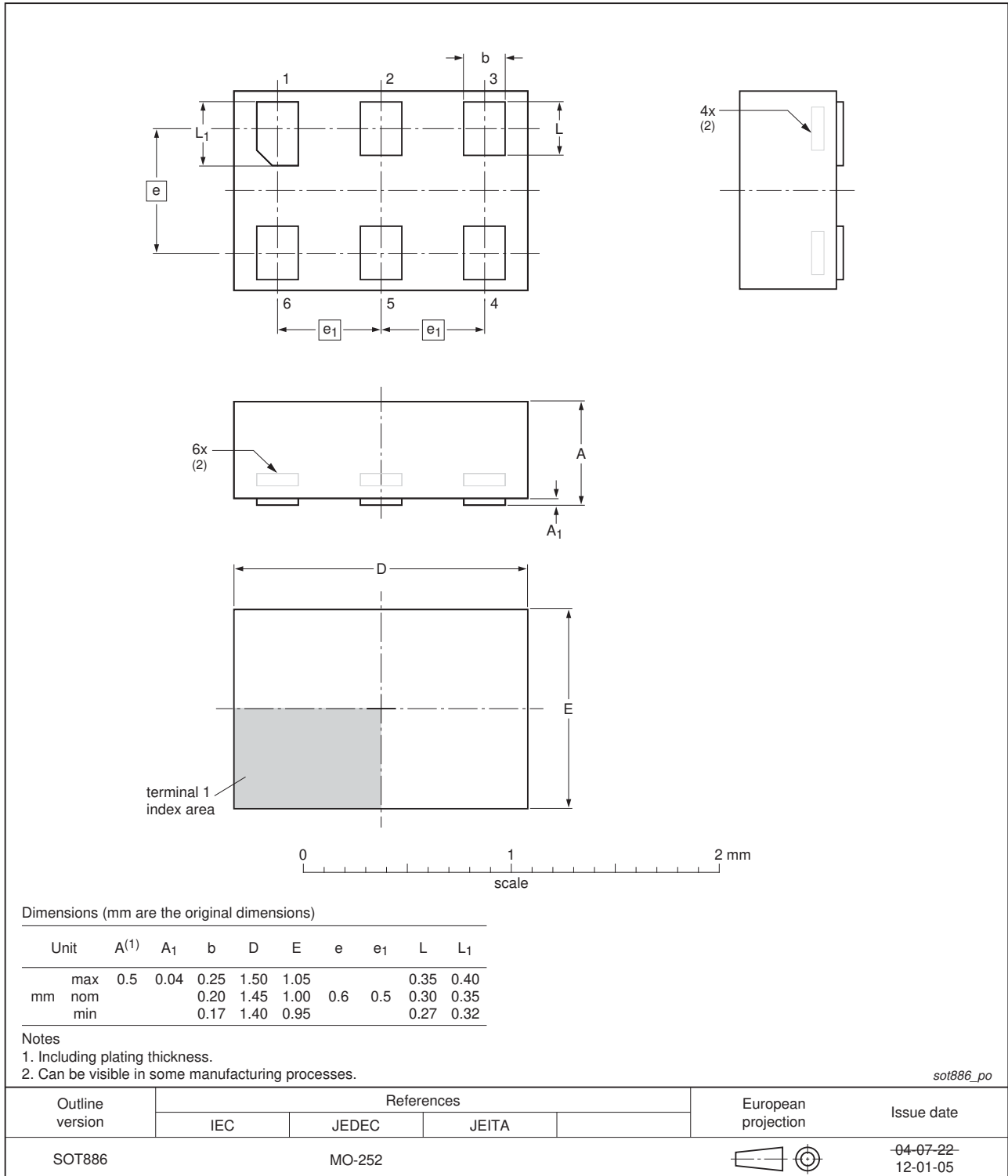


Fig 10. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm

SOT891

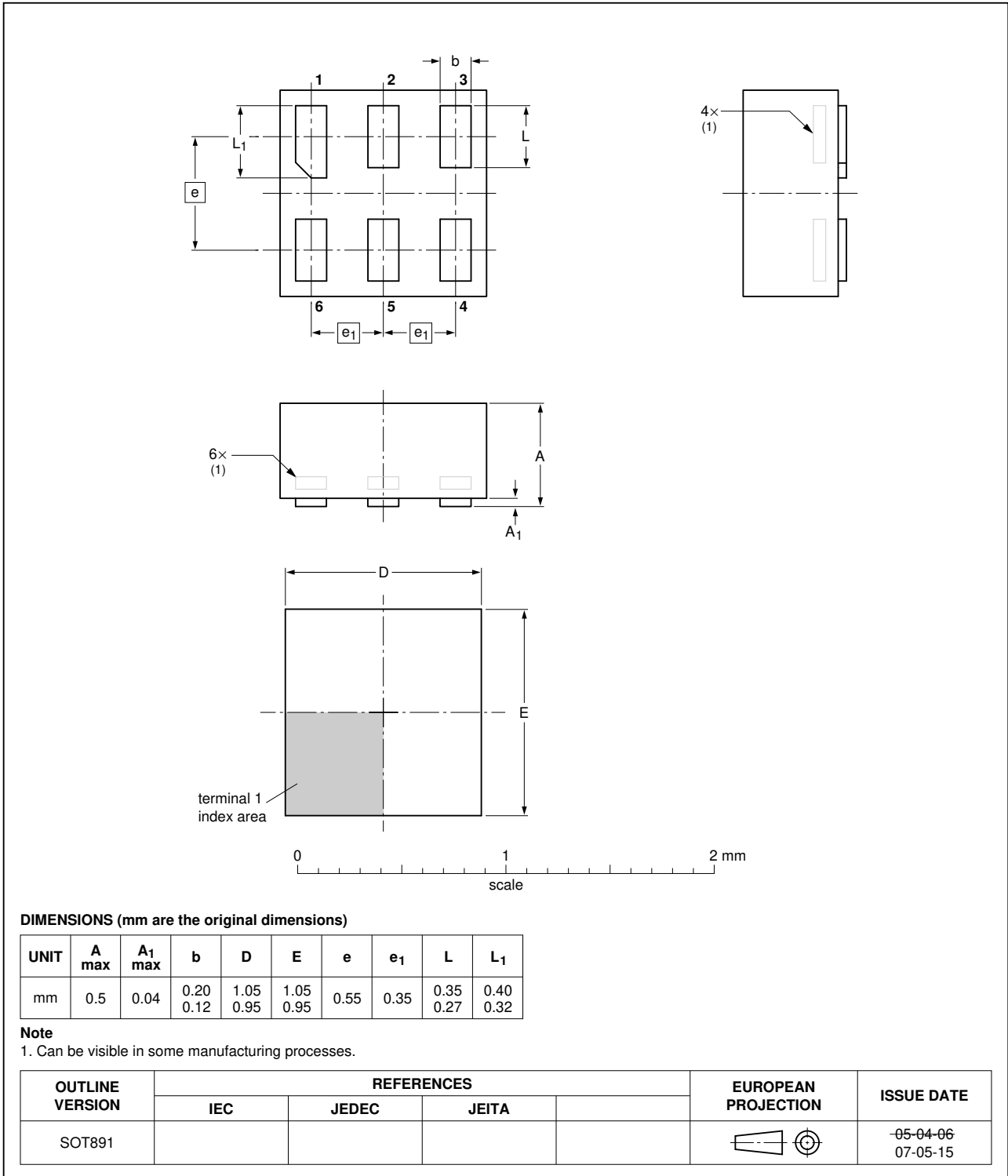


Fig 11. Package outline SOT891 (XSON6)

**XSON6: extremely thin small outline package; no leads;  
6 terminals; body 0.9 x 1.0 x 0.35 mm**

SOT1115

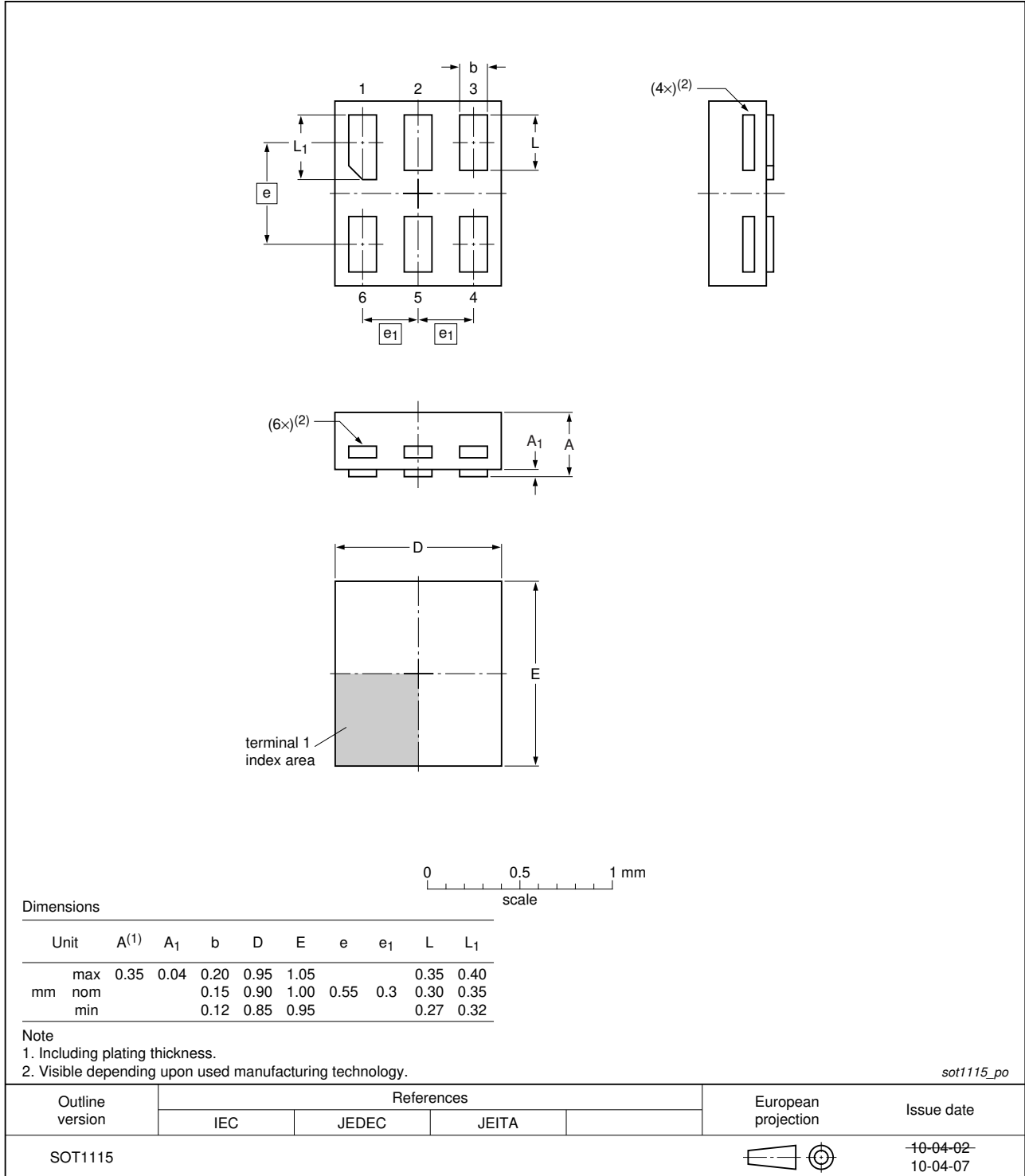


Fig 12. Package outline SOT1115 (XSON6)



**XSON6: extremely thin small outline package; no leads;  
6 terminals; body 1.0 x 1.0 x 0.35 mm**

SOT1202

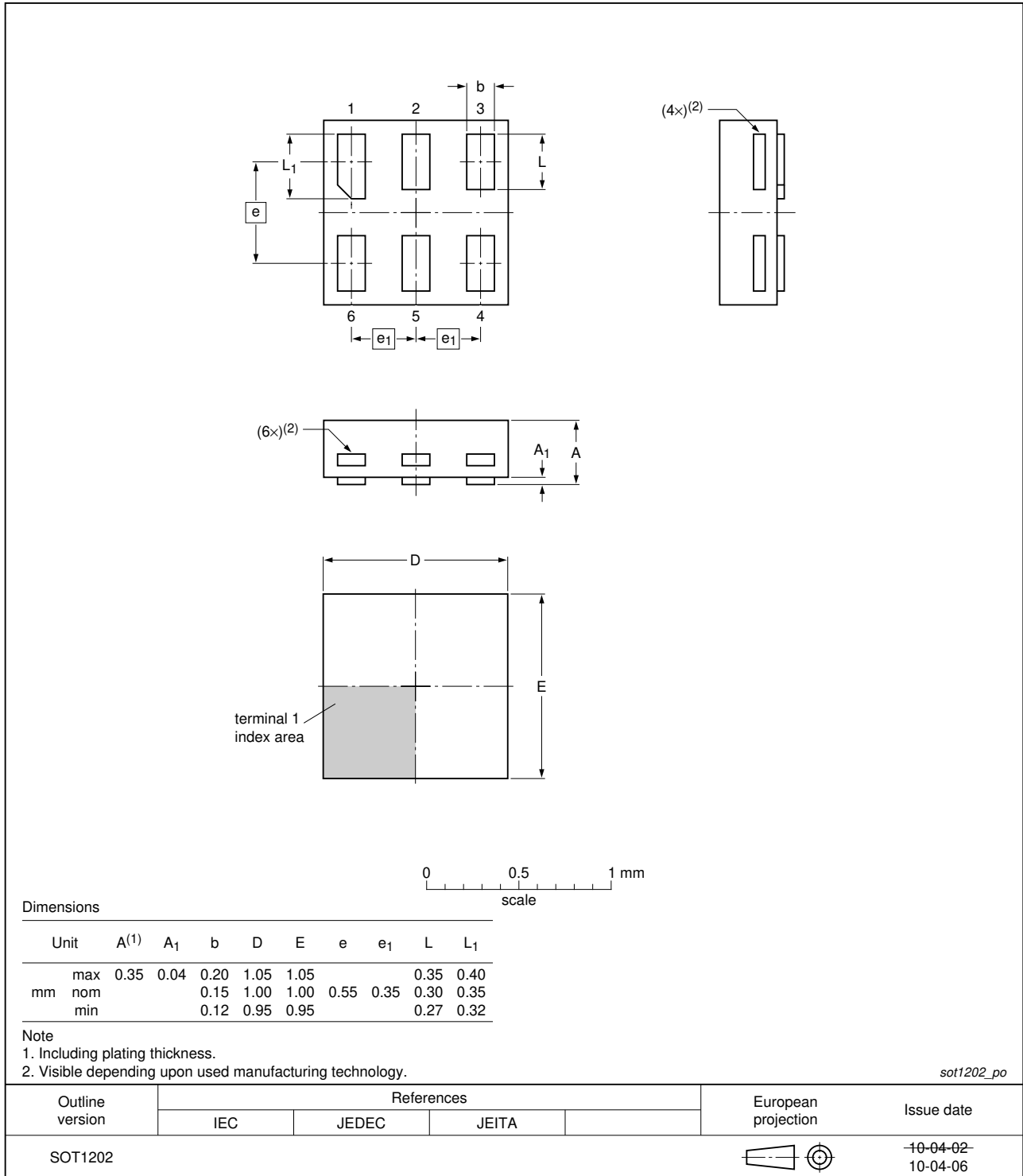


Fig 13. Package outline SOT1202 (XSON6)

## 14. Abbreviations

Table 11. Abbreviations

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| HBM     | Human Body Model        |
| MM      | Machine Model           |

## 15. Revision history

Table 12. Revision history

| Document ID    | Release date  | Data sheet status  | Change notice | Supersedes     |
|----------------|---|--------------------|---------------|----------------|
| 74AUP1G386 v.6 | 20120731  | Product data sheet | -             | 74AUP1G386 v.5 |
| Modifications: | <ul style="list-style-type: none"> <li>Package outline drawing of SOT886 (<a href="#">Figure 10</a>) modified.</li> </ul> |                    |               |                |
| 74AUP1G386 v.5 | 20111128  | Product data sheet | -             | 74AUP1G386 v.4 |
| Modifications: | <ul style="list-style-type: none"> <li>Legal pages updated.</li> </ul>  |                    |               |                |
| 74AUP1G386 v.4 | 20100805  | Product data sheet | -             | 74AUP1G386 v.3 |
| 74AUP1G386 v.3 | 20090702  | Product data sheet | -             | 74AUP1G386 v.2 |
| 74AUP1G386 v.2 | 20080110  | Product data sheet | -             | 74AUP1G386 v.1 |
| 74AUP1G386 v.1 | 20061129  | Product data sheet | -             | -              |

## 16. Legal information

### 16.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## 18. Contents

|      |  |    |
|------|--|----|
| 1    | General description . . . . .              | 1  |
| 2    | Features and benefits . . . . .            | 1  |
| 3    | Ordering information . . . . .             | 2  |
| 4    | Marking . . . . .                          | 2  |
| 5    | Functional diagram . . . . .               | 2  |
| 6    | Pinning information . . . . .              | 3  |
| 6.1  | Pinning . . . . .                          | 3  |
| 6.2  | Pin description . . . . .                  | 3  |
| 7    | Functional description . . . . .           | 4  |
| 8    | Limiting values . . . . .                  | 4  |
| 9    | Recommended operating conditions . . . . . | 4  |
| 10   | Static characteristics . . . . .           | 5  |
| 11   | Dynamic characteristics . . . . .          | 8  |
| 12   | Waveforms . . . . .                        | 9  |
| 13   | Package outline . . . . .                  | 11 |
| 14   | Abbreviations . . . . .                    | 16 |
| 15   | Revision history . . . . .                 | 16 |
| 16   | Legal information . . . . .                | 17 |
| 16.1 | Data sheet status . . . . .                | 17 |
| 16.2 | Definitions . . . . .                      | 17 |
| 16.3 | Disclaimers . . . . .                      | 17 |
| 16.4 | Trademarks . . . . .                       | 18 |
| 17   | Contact information . . . . .              | 18 |
| 18   | Contents . . . . .                         | 19 |

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